

FCAB21520L1

Gate resistor installed Dual N-channel MOS FET

For lithium-ion secondary battery protection circuits

■ Features

- Source-source ON resistance:RSS(on) typ. = 1.6 mΩ (VGS = 3.8 V)
- CSP(Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1)

■ Marking Symbol: 7T

■ Packaging

Embossed type (Thermo-compression sealing) : 1 000 pcs / reel (standard)

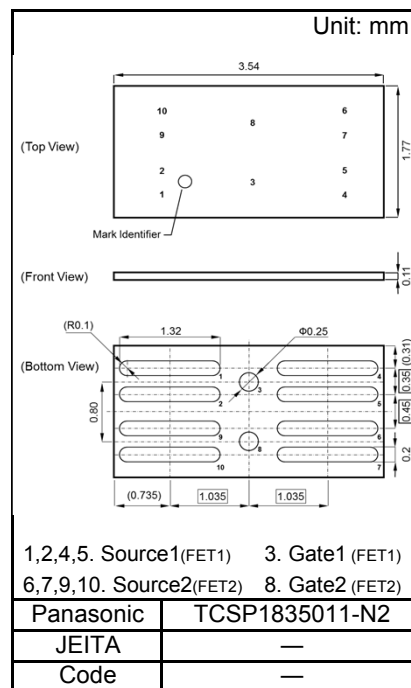
■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Symbol	Rating	Unit
Source-source Voltage		VSS	12	V
Gate-source Voltage		VGS	±8	V
Source Current	DC ^{*1}	IS1	16	A
	DC ^{*2}	IS2	35	A
	Pulse ^{*3}	ISp	160	A
Total Power Dissipation	DC ^{*1}	PD1	0.54	W
	DC ^{*2}	PD2	3.8	W
Channel Temperature		Tch	150	°C
Storage Temperature Range		Tstg	-55 to +150	°C
Thermal Resistance (ch-a)		Rth ^{*1}	232	°C/W
		Rth ^{*2}	33	°C/W

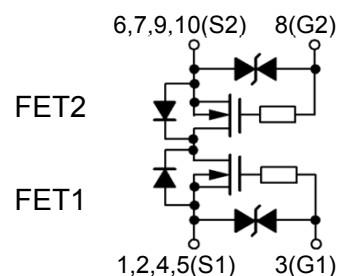
Note *1 Mounted on FR4 board (25.4 mm × 25.4 mm × t1.0 mm)
using the minimum recommended pad size (36 μm Copper).

*2 Mounted on Ceramic substrate (70 mm × 70 mm × t1.0 mm).

*3 t = 10 μs, Duty Cycle ≤ 1 %



Equivalent Circuit



■ Electrical Characteristics Ta = 25 °C ± 3 °C

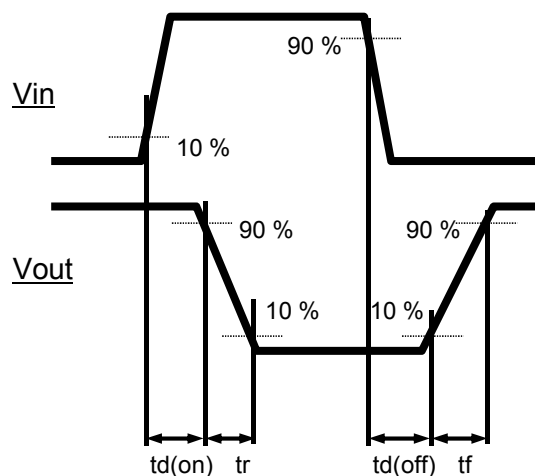
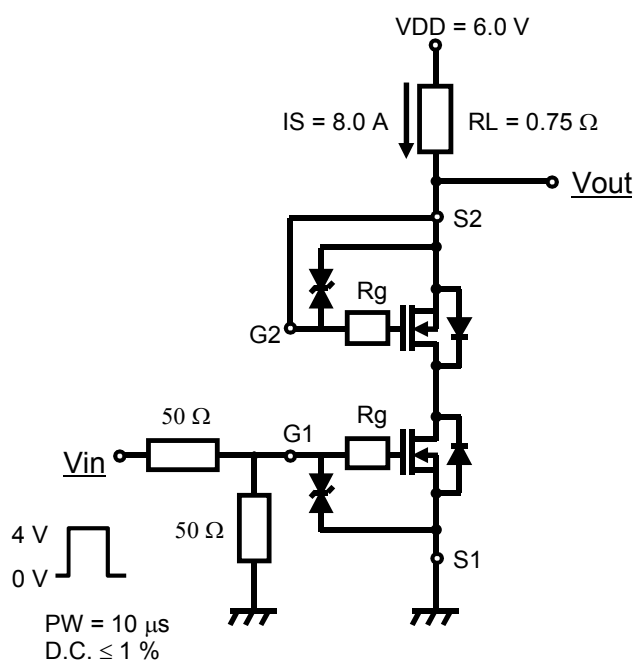
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Source-source Breakdown Voltage	VSSS	IS = 1.0 mA, VGS = 0 V	12			V
Zero Gate Voltage Source Current	ISSS	VSS = 12 V, VGS = 0 V			1.0	μA
Gate-source Leakage Current	IGSS	VGS = ±8 V, VSS = 0 V			±10	μA
		VGS = ±5 V, VSS = 0 V			±1.0	
Gate-source Threshold Voltage	Vth	IS = 1.64 mA, VSS = 10 V	0.35	0.90	1.40	V
Source-source On-state Resistance	RSS(on)1	IS = 8.0 A, VGS = 4.5 V	1.1	1.45	2.0	mΩ
	RSS(on)2	IS = 8.0 A, VGS = 3.8 V	1.15	1.6	2.1	
	RSS(on)3	IS = 8.0 A, VGS = 3.1 V	1.2	1.8	3.0	
	RSS(on)4	IS = 8.0 A, VGS = 2.5 V	1.4	2.3	4.5	
Body Diode Forward Voltage	VF(s-s)	IF = 8.0 A, VGS = 0 V		0.7	1.2	V
Input Capacitance ^{*1}	Ciss	VSS = 10 V, VGS = 0 V, f = 1 kHz		5250		pF
Output Capacitance ^{*1}	Coss			700		
Reverse Transfer Capacitance ^{*1}	Crss			630		
Turn-on Delay Time ^{*1,*2}	td(on)	VDD = 6.0 V, VGS = 0 to 4.0 V		1.5		μs
Rise Time ^{*1,*2}	tr	IS = 8.0 A		2.6		
Turn-off Delay Time ^{*1,*2}	td(off)	VDD = 6.0 V, VGS = 4.0 to 0 V		6.8		μs
Fall Time ^{*1,*2}	tf	IS = 8.0 A		4.1		
Total Gate Charge ^{*1}	Qg	VDD = 6.0 V		38		nC
Gate-source Charge ^{*1}	Qgs	VGS = 0 to 4.0 V		20		
Gate-drain Charge ^{*1}	Qgd	IS = 8.0 A		10		

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

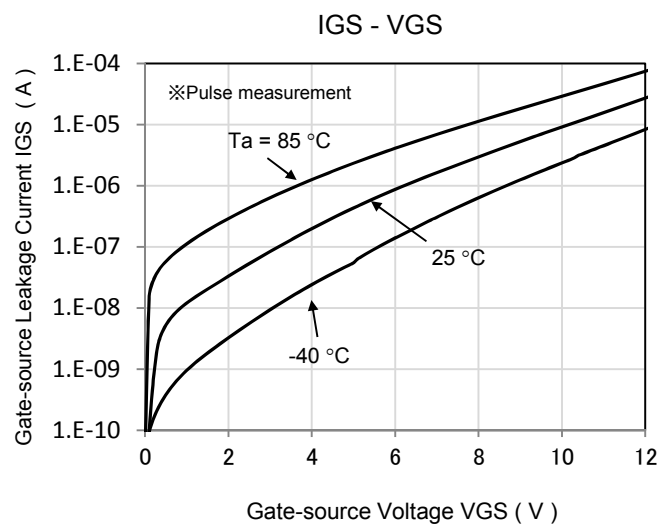
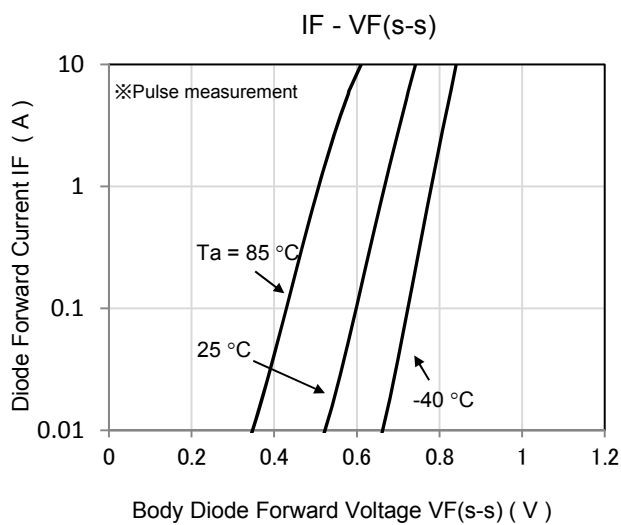
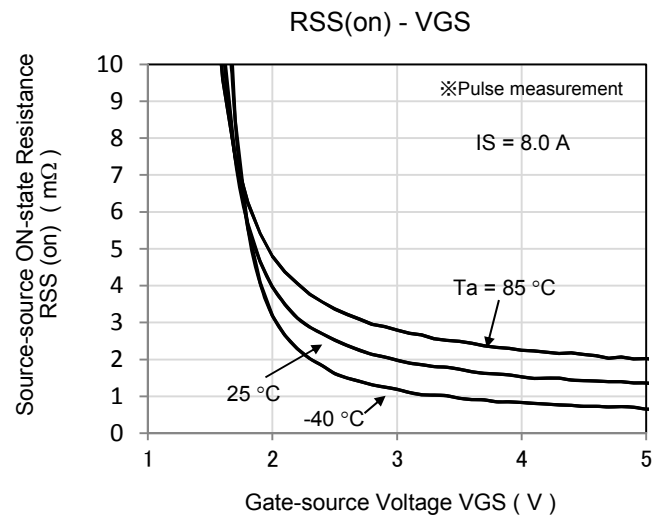
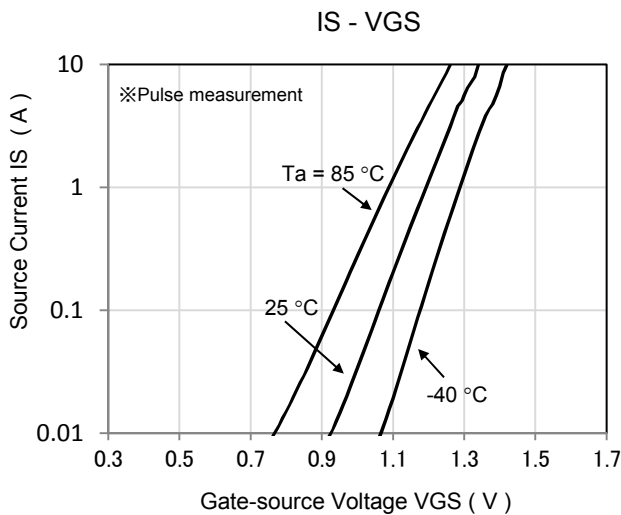
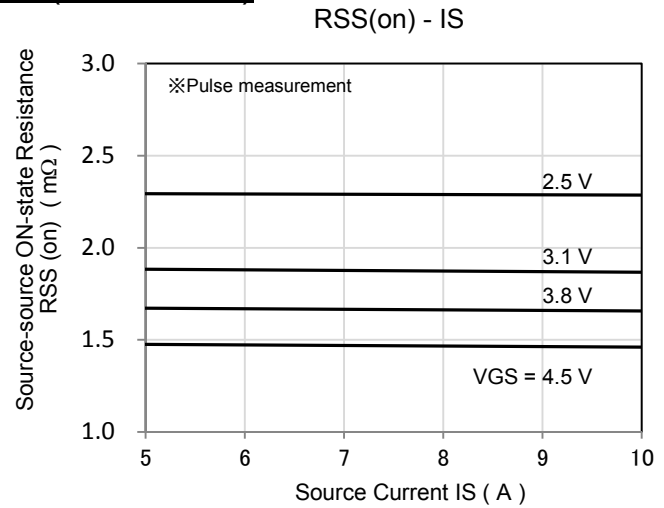
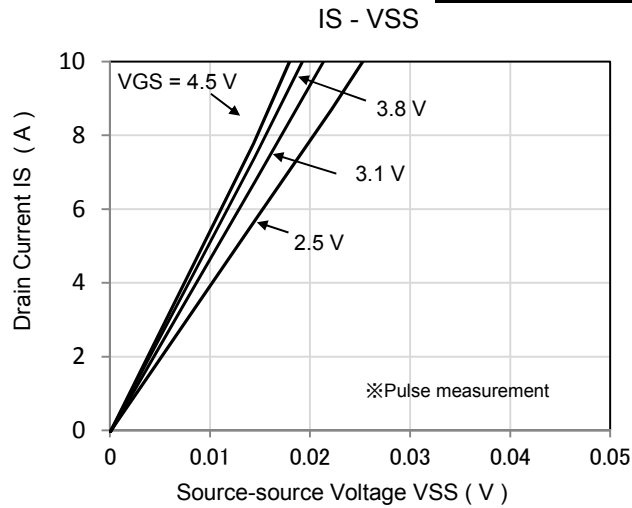
*1 Guaranteed by design, not subject to production testing

*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

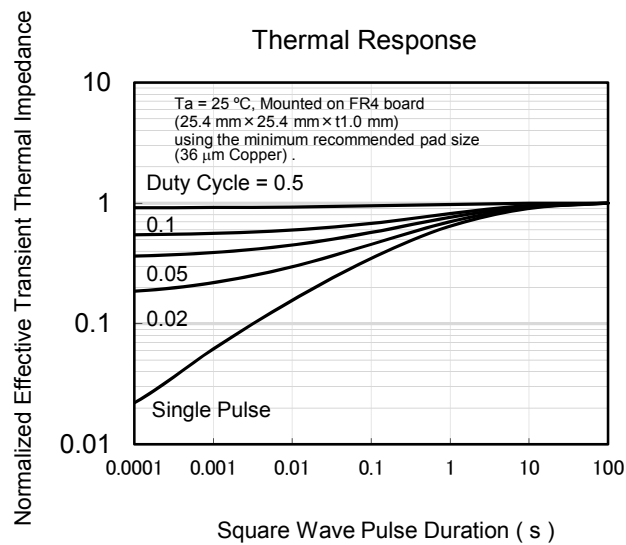
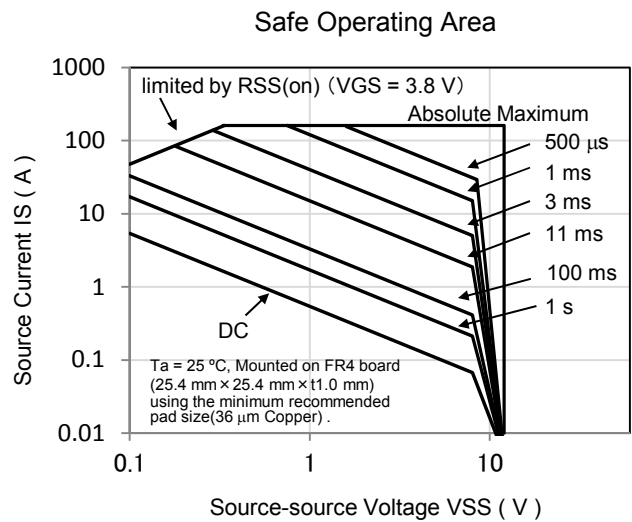
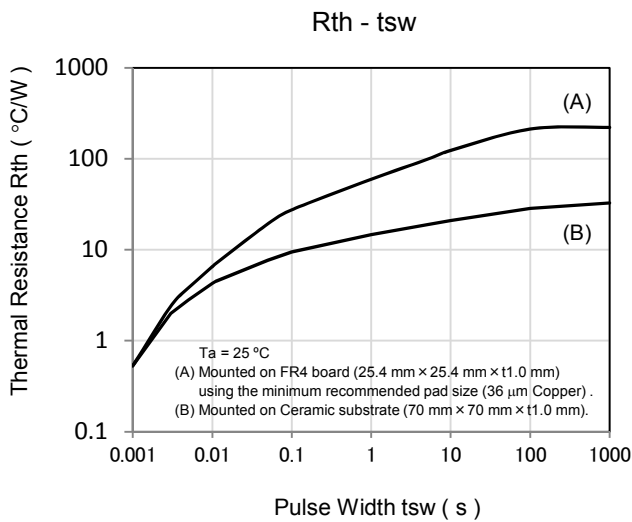
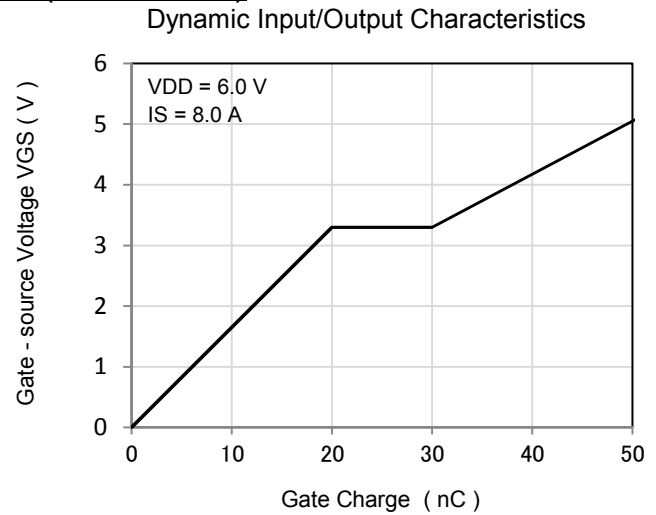
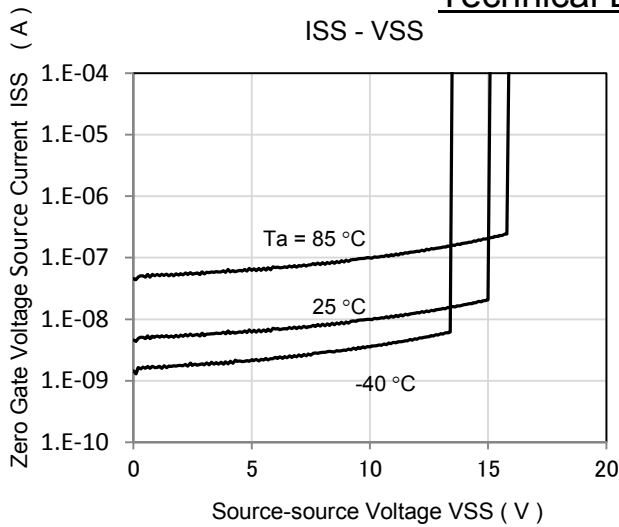
Note2: Measurement circuit



Technical Data (reference)



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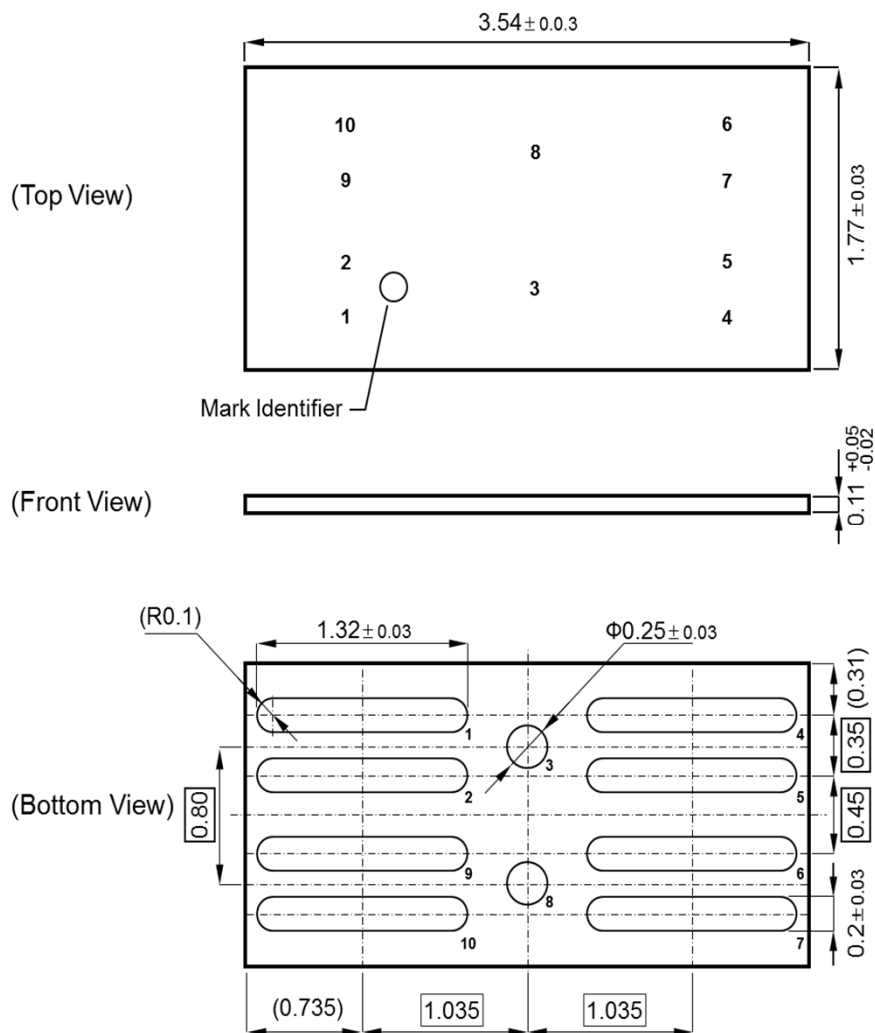


Panasonic

MOS FET
FCAB21520L1

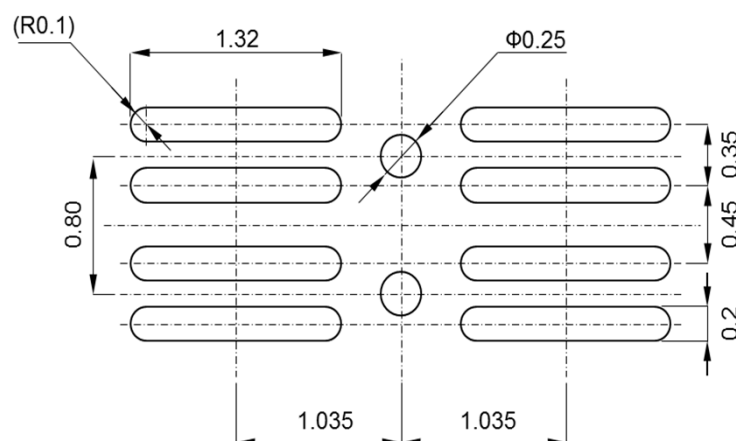
■ Outline

Unit : mm



■ Land Pattern (Reference)

Unit : mm



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